

TC74VHC367FN,TC74VHC368FN**Hex Bus Buffer**

TC74VHC367FN	Non-Inverted, 3-State Outputs
TC74VHC368FN	Inverted, 3-State Outputs

The TC74VHC367 and 368 are advanced high speed CMOS HEX BUS BUFFERs fabricated with silicon gate C²MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

They contain six buffers; four buffers are controlled by an enable input (\bar{G}_1), and the other two buffers are controlled by another enable input (\bar{G}_2). The outputs of each buffer group are enabled when \bar{G}_1 and/or \bar{G}_2 inputs are held low; if held high, these outputs are in a high impedance state.

The TC74VHC367 is a non-inverting output type, while the TC74VHC368 is an inverting output type.

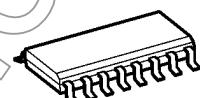
An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High speed: $t_{pd} = 3.8$ ns (typ.) at $V_{CC} = 5$ V
- Low power dissipation: $I_{CC} = 4$ μ A (max) at $T_a = 25^\circ C$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\%$ V_{CC} (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2 V to 5.5 V
- Low noise: $VO_{LP} = 0.8$ V (max)
- Pin and function compatible with 74ALS367/368

Note: The JEDEC SOP (FN) is not available in Japan.

TC74VHC367FN, TC74VHC368FN



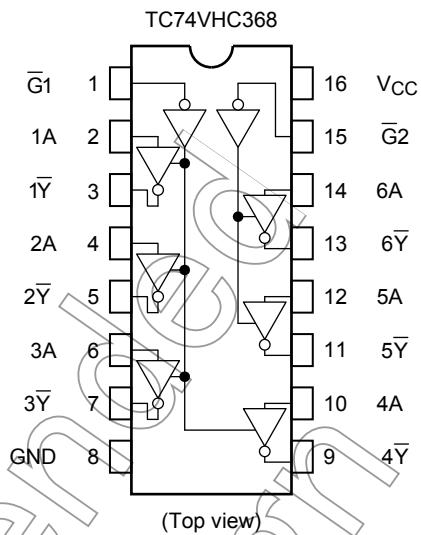
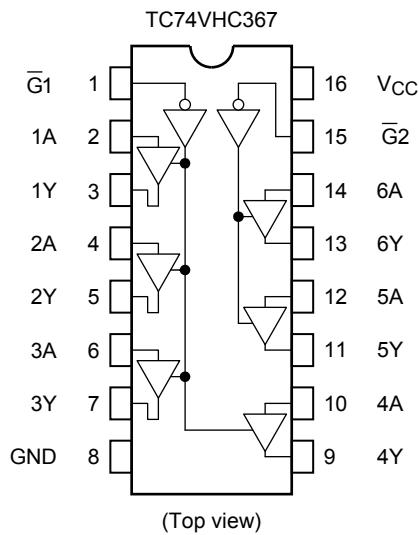
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Weight

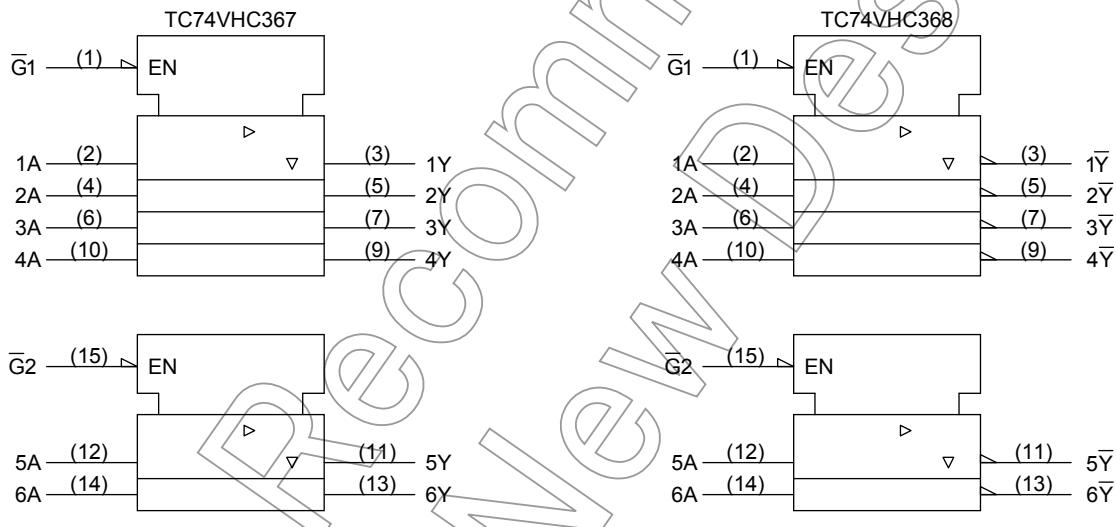
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0.13 g (typ.)

Pin Assignment



IEC Logic Symbol



Truth Table

Inputs		Outputs	
\bar{G}	A	Y (367)	\bar{Y} (368)
L	L	L	H
L	H	H	L
H	X	Z	Z

X: Don't care

Z: High impedance

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5 to 7.0	V
DC input voltage	V_{IN}	-0.5 to 7.0	V
DC output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}	-20	mA
Output diode current	I_{OK}	± 20	mA
DC output current	I_{OUT}	± 25	mA
DC V_{CC} /ground current	I_{CC}	± 50	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{STG}	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{OPR}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100 (V _{CC} = 3.3 ± 0.3 V) 0 to 20 (V _{CC} = 5 ± 0.5 V)	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
			V _{CC} (V)	Min	Typ.	Max	Min	Max		
High-level input voltage	V _{IH}	—	2.0 3.0 to 5.5	1.50 V _{CC} × 0.7	— —	— —	1.50 V _{CC} × 0.7	— —	V	
Low-level input voltage	V _{IL}	—	2.0 3.0 to 5.5	— —	— —	0.50 V _{CC} × 0.3	— —	0.50 V _{CC} × 0.3	V	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 µA	2.0 3.0 4.5	1.9 2.9 4.4	2.0 3.0 4.5	— — —	1.9 2.9 4.4	V	
			I _{OH} = -4 mA	3.0 4.5	2.58 3.94	— —	— —	2.48 3.80		
			I _{OH} = -8 mA	—	—	— —	— —	— —		
		V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 µA	2.0 3.0 4.5	— — —	0.0 0.0 0.0	0.1 0.1 0.1	0.1 0.1 0.1	V	
			I _{OL} = 4 mA	3.0	—	—	0.36	—		
			I _{OL} = 8 mA	4.5	—	—	0.36	—		
3-state output off-state current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND	—	5.5	—	—	±0.25	—	±2.50	µA
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND	0 to 5.5	—	—	—	±0.1	—	±1.0	µA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND	—	5.5	—	—	4.0	—	40.0	µA

Not for New

AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit	
			V _{CC} (V)	C _L (pF)	Min	Typ.	Max	Min	Max		
Propagation delay time (TC74VHC367)	t _{pLH}	—	3.3 ± 0.3	15	—	5.9	8.3	1.0	10.0	ns	
				50	—	8.4	11.8	1.0	13.5		
	t _{pHL}		5.0 ± 0.5	15	—	4.1	5.9	1.0	7.0		
				50	—	5.6	7.9	1.0	9.0		
	t _{pLH}	—	3.3 ± 0.3	15	—	5.3	7.5	1.0	9.0		
				50	—	7.8	11.0	1.0	12.5		
	t _{pHL}		5.0 ± 0.5	15	—	3.8	5.5	1.0	6.5		
				50	—	5.3	7.5	1.0	8.5		
3-state output enable time	t _{pZL}	R _L = 1 kΩ	3.3 ± 0.3	15	—	6.8	10.5	1.0	12.5	ns	
				50	—	9.3	14.0	1.0	16.0		
	t _{pZH}		5.0 ± 0.5	15	—	4.8	7.2	1.0	8.5		
				50	—	6.3	9.2	1.0	10.5		
	t _{pLZ}	R _L = 1 kΩ	3.3 ± 0.3	50	—	9.9	13.6	1.0	15.5		
			5.0 ± 0.5	50	—	6.3	9.2	1.0	10.5		
	t _{osLH}	(Note 1)	3.3 ± 0.3	50	—	—	1.5	—	1.5		
			5.0 ± 0.5	50	—	—	1.0	—	1.0		
Input capacitance	C _{IN}				—	4	10	—	10	pF	
Output capacitance	C _{OUT}		—		—	6	—	—	—	pF	
Power dissipation capacitance	C _{PD}			(Note 2)	—	19	—	—	—	pF	

Note 1: Parameter guaranteed by design

$$t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|$$

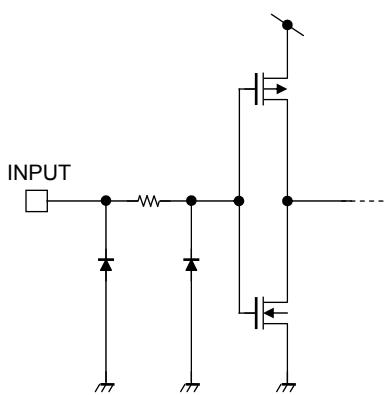
Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (\text{opr})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 6 \text{ (per-bit)}$$

Noise Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C		Unit
			V _{CC} (V)	Typ.	Limit		
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.4	0.8	V	
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.4	-0.8	V	
Minimum high level dynamic input voltage	V _{IHD}	C _L = 50 pF	5.0	—	3.5	V	
Maximum low level dynamic input voltage	V _{ILD}	C _L = 50 pF	5.0	—	1.5	V	

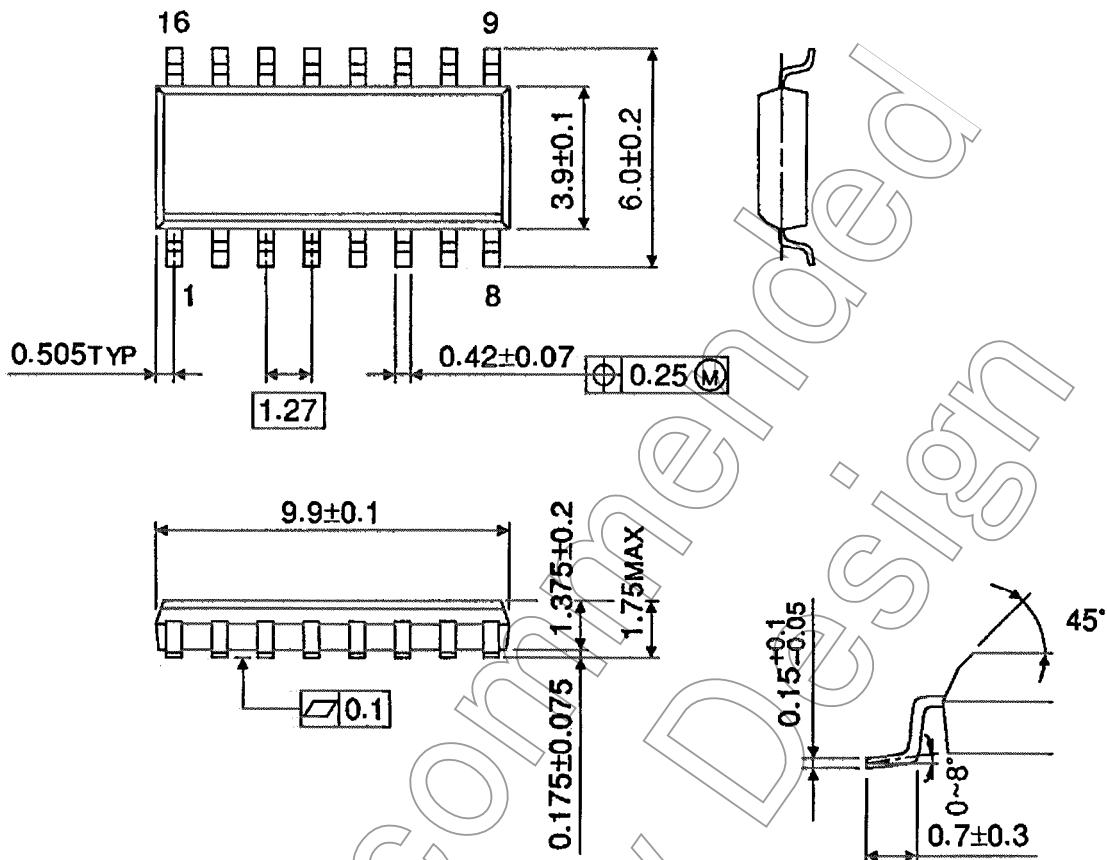
Input Equivalent Circuit

Not Recommended
for New Design

Package Dimensions (Note)

SOL16-P-150-1.27

Unit : mm



Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

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